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## 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>GE</sub> = 0)	600	V
I <sub>C</sub> <sup>(1)</sup>	Collector current (continuous) at T <sub>C</sub> = 25 °C	14	Α
I <sub>C</sub> <sup>(1)</sup>	Collector current (continuous) at T <sub>C</sub> = 100 °C	6	Α
I <sub>CL</sub> <sup>(2)</sup>	Turn-off latching current	18	Α
I <sub>CP</sub> <sup>(3)</sup>	Pulsed collector current	18	Α
V <sub>GE</sub>	Gate-emitter voltage	±20	٧
I <sub>F</sub>	Diode RMS forward current at T <sub>C</sub> = 25 °C	7	Α
I <sub>FSM</sub>	Surge non repetitive forward current t <sub>p</sub> = 10 ms sinusoidal	20	А
P <sub>TOT</sub>	Total dissipation at T <sub>C</sub> = 25 °C	56	W
V <sub>ISO</sub>	$V_{\rm ISO}$ Insulation withstand voltage (RMS) from all three leads to external heat sink (t = 1 s; $T_{\rm C}$ = 25 °C)		
T <sub>j</sub>	Operating junction temperature	– 55 to 150	°C

1. Calculated according to the iterative formula:

$$I_{C}(T_{C}) = \frac{T_{j(max)} - T_{C}}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_{C}(T_{C}))}$$

- 2. Vclamp = 80%,(V<sub>CES</sub>), Tj =150°C, R<sub>G</sub> = 10  $\Omega$ , V<sub>GE</sub> = 15 V
- 3. Pulse width limited by max junction temperature allowed

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
D	Thermal resistance junction-case IGBT max.	2.2	°C/W
R <sub>thj-case</sub>	Thermal resistance junction-case diode max.	4	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-ambient max.	62.5	°C/W

#### 2 Electrical characteristics

 $T_{CASE} = 25$  °C unless otherwise specified.

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>(BR)CES</sub>	Collector-emitter breakdown voltage (V <sub>GE</sub> = 0)	I <sub>C</sub> = 1 mA	600			V
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	hitter saturation $V_{GE} = 15 \text{ V}, I_{C} = 1.5 \text{ A}$ $V_{GE} = 15 \text{ V}, I_{C} = 3 \text{ A}$ $V_{GE} = 15 \text{ V}, I_{C} = 3 \text{ A}, T_{C} = 125^{\circ}\text{C}$		1.9 2.2 2	2.9	V V V
V <sub>GE(th)</sub>	Gate threshold voltage	V <sub>CE</sub> = V <sub>GE</sub> , I <sub>C</sub> = 250 μA	3.75		5.75	V
I <sub>CES</sub>	Collector cut-off current (V <sub>GE</sub> = 0)	V <sub>CE</sub> = 600 V V <sub>CE</sub> = 600 V, T <sub>C</sub> = 125 °C			50 5	μA mA
I <sub>GES</sub>	Gate-emitter leakage current (V <sub>CE</sub> = 0)	V <sub>GE</sub> = ±20 V			±100	nA
9 <sub>fs</sub>	Forward transconductance	$V_{CE} = 15 V_{,} I_{C} = 3 A$		3		S

Table 5. Dynamic electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C <sub>ies</sub> C <sub>oes</sub> C <sub>res</sub>	Input capacitance Output capacitance Reverse transfer capacitance	V <sub>CE</sub> = 25 V, f = 1 MHz, V <sub>GE</sub> = 0		208 32.5 5.4		pF pF pF
Q <sub>g</sub> Q <sub>ge</sub> Q <sub>gc</sub>	Total gate charge Gate-emitter charge Gate-collector charge	$V_{CE}$ = 390 V, $I_{C}$ = 3 A, $V_{GE}$ = 15 V (see Figure 17)		12 2.6 4.9		nC nC nC

Table 6. Switching on/off (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>d(on)</sub> t <sub>r</sub> (di/dt) <sub>on</sub>	Turn-on delay time Current rise time Turn-on current slope	$V_{CC}$ = 390 V, $I_{C}$ = 3 A $R_{G}$ = 10 $\Omega$ , $V_{GE}$ = 15 V (see Figure 18)		6.7 3.7 930		ns ns A/µs
t <sub>d(on)</sub> t <sub>r</sub> (di/dt) <sub>on</sub>	Turn-on delay time Current rise time Turn-on current slope	$V_{CC} = 390 \text{ V}, I_{C} = 3 \text{ A}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ $T_{C} = 125 \text{ °C} \text{ (see Figure 18)}$		6.5 4 820		ns ns A/µs
$t_r(V_{off})$ $t_d(_{off})$ $t_f$	Off voltage rise time Turn-off delay time Current fall time	$V_{CC}$ = 390 V, $I_{C}$ = 3 A, $R_{GE}$ = 10 $\Omega$ , $V_{GE}$ = 15 V (see Figure 18)		17 46 47		ns ns ns
t <sub>r</sub> (V <sub>off</sub> ) t <sub>d</sub> ( <sub>off</sub> ) t <sub>f</sub>	Off voltage rise time Turn-off delay time Current fall time	$V_{CC} = 390 \text{ V, } I_{C} = 3 \text{ A,}$ $R_{GE} = 10 \Omega, V_{GE} = 15 \text{ V,}$ $T_{C} = 125 \text{ °C (see Figure 18)}$		35 67 55		ns ns ns

Table 7. Switching energy (inductive load)

Symbol	ymbol Parameter Test conditions		Min.	Тур.	Max.	Unit
E <sub>on</sub> <sup>(1)</sup>	Turn-on switching losses	$V_{CC} = 390 \text{ V}, I_{C} = 3 \text{ A}$		46.5		μJ
E <sub>off</sub> <sup>(2)</sup>	Turn-off switching losses	$R_G = 10 \Omega, V_{GE} = 15 V$		23.5		μJ
E <sub>ts</sub>	Total switching losses	(see Figure 18)		70		μJ
E <sub>on</sub> (1)	Turn-on switching losses	$V_{CC} = 390 \text{ V}, I_{C} = 3 \text{ A}$		67.5		μJ
E <sub>off</sub> <sup>(2)</sup>	Turn-off switching losses	$R_G = 10 \Omega$ , $V_{GE} = 15 V$ ,		46		μJ
E <sub>ts</sub>	Total switching losses	T <sub>C</sub> = 125 °C (see Figure 18)		113.5		μJ

Eon is the turn-on losses when a typical diode is used in the test circuit in (see Figure 19). If the IGBT is
offered in a package with a co-pak diode, the co-pack diode is used as external diode. IGBTs & Diode are
at the same temperature (25°C and 125°C)

Table 8. Turn-off with snubber

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>f</sub> E <sub>off</sub> <sup>(1)</sup>	Current fall time Turn-off switching losses	$\begin{split} &V_{CC}=200 \text{ V, } I_{C}=1.5 \text{ A} \\ &R_{G}=22 \Omega\text{, } V_{clamp}\text{=}400 \text{ V,} \\ &L\text{=}1 \text{ mH, C-snubber}=2.7 \text{ nF} \\ &\textit{(see Figure 18)} \end{split}$		16 1.6		ns µJ
t <sub>f</sub> E <sub>off</sub> <sup>(1)</sup>	Current fall time Turn-off switching losses	$\begin{split} &V_{CC} = 200 \text{ V, } I_{C} = 1.5 \text{ A} \\ &R_{G} = 22 \Omega, V_{clamp} = 400 \text{ V,} \\ &L=1 \text{ mH, C-snubber= } 2.7 \text{ nF,} \\ &T_{C} = 100 \text{ °C } \textit{(see Figure 18)} \end{split}$		19 3.5		ns µJ

<sup>1.</sup> Turn-off losses include also the tail of the collector current

<sup>2.</sup> Turn-off losses include also the tail of the collector current

Unit **Symbol Parameter Test conditions** Min. Тур. Max.  $I_F = 1 A$ 1.3 ٧ I<sub>F</sub>=3 A 1.35 V  $V_{\mathsf{F}}$ Forward on-voltage I<sub>F</sub>=3 A,Tc=125 °C 1.15 ٧  $I_F = 3 A, V_R = 40 V,$ Reverse recovery time 50 ns t<sub>rr</sub>  $di/dt = 100 A/\mu s$ Reverse recovery charge 55 nC  $Q_{rr}$ (see Figure 19) 2.2 Α Reverse recovery current  $I_{rrm}$  $I_F = 3 A, V_R = 40 V,$ 80  $t_{rr}$ Reverse recovery time ns  $T_C = 125 \, ^{\circ}C$ , di/dt = 100 $Q_{rr}$ Reverse recovery charge 105 nC A/μs 2.7 Reverse recovery current Α  $I_{rrm}$ (see Figure 19)

Table 9. Collector-emitter diode

#### 2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

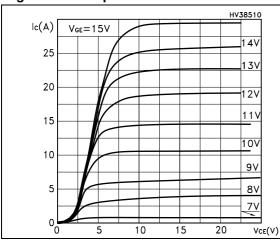


Figure 3. Transfer characteristics

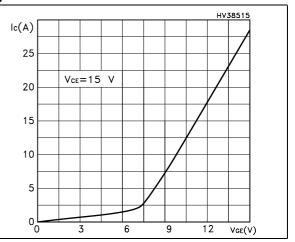


Figure 4. Transconductance

Figure 5. Collector-emitter on voltage vs. temperature

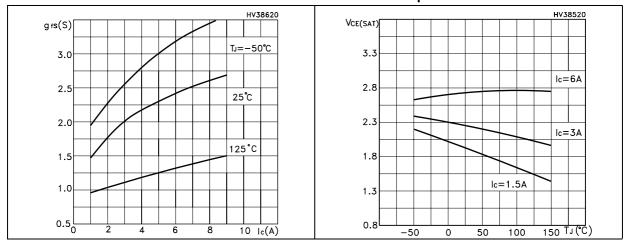
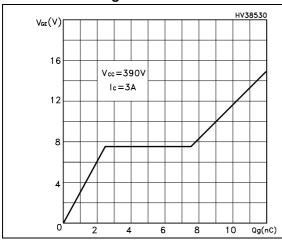


Figure 6. Gate charge vs. gate-source voltage

Figure 7. Capacitance variations



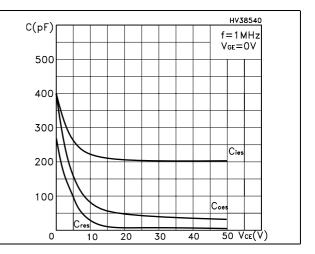
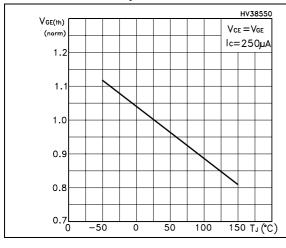


Figure 8. Normalized gate threshold voltage Figure 9. vs. temperature

gure 9. Collector-emitter on voltage vs. collector current



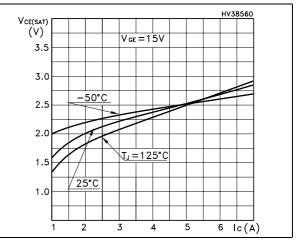
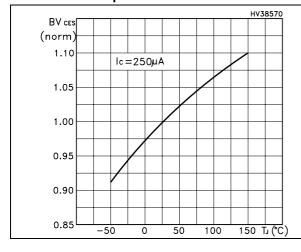
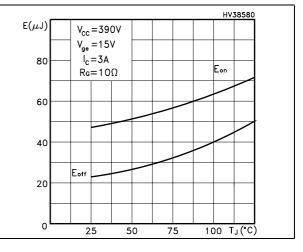


Figure 10. Normalized breakdown voltage vs. Figure 11. Switching losses vs. temperature temperature





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Figure 12. Switching losses vs. gate resistance

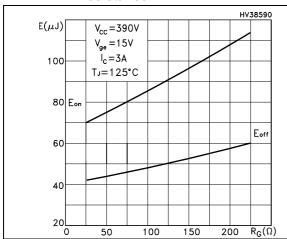


Figure 13. Switching losses vs. collector current

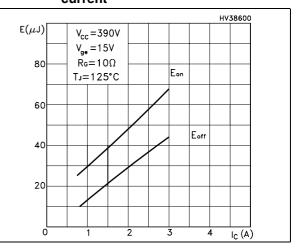
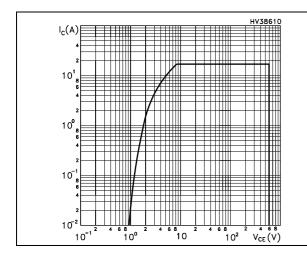
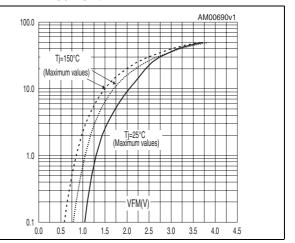


Figure 14. Turn-off SOA

Figure 15. Forward voltage drop vs. forward current





1ΚΩ

V<sub>G</sub>

#### 3 Test circuit

Figure 16. Test circuit for inductive load switching

Figure 17. Gate charge test circuit

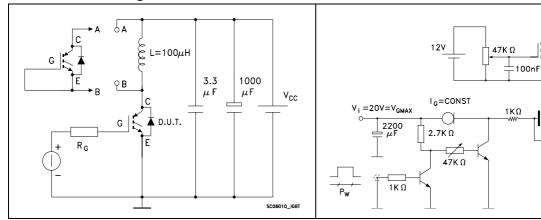
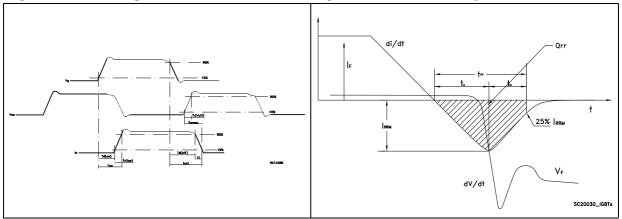


Figure 18. Switching waveform

Figure 19. Diode recovery time waveform



### 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

Table 10. TO-220 type A mechanical data

Dim.		mm	
Dilli.	Min.	Тур.	Max.
Α	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
Е	10		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95

Figure 20. TO-220 type A drawing

Table 11. D<sup>2</sup>PAK (TO-263) mechanical data

Dim		mm	
Dim.	Min.	Тур.	Max.
Α	4.40		4.60
A1	0.03		0.23
b	0.70		0.93
b2	1.14		1.70
С	0.45		0.60
c2	1.23		1.36
D	8.95		9.35
D1	7.50		
E	10		10.40
E1	8.50		
е		2.54	
e1	4.88		5.28
Н	15		15.85
J1	2.49		2.69
L	2.29		2.79
L1	1.27		1.40
L2	1.30		1.75
R		0.4	
V2	0°		8°

SEATING PLANE

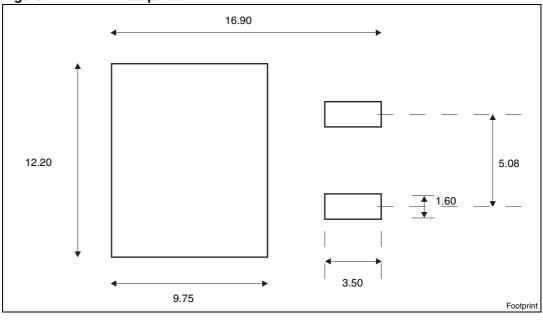
COPLANARITY A1

R

GAUGE PLANE

Figure 21. D<sup>2</sup>PAK (TO-263) drawing





a. All dimension are in millimeters

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## 5 Packaging mechanical data

Table 12. D<sup>2</sup>PAK (TO-263) tape and reel mechanical data

	Таре			Reel	
Dim.	mm		Dim.	m	ım
Dim.	Min.	Max.	– Dim.	Min.	Max.
A0	10.5	10.7	Α		330
В0	15.7	15.9	В	1.5	
D	1.5	1.6	С	12.8	13.2
D1	1.59	1.61	D	20.2	
Е	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	Т		30.4
P0	3.9	4.1			
P1	11.9	12.1		Base qty	1000
P2	1.9	2.1		Bulk qty	1000
R	50				
Т	0.25	0.35			
W	23.7	24.3			

Figure 23. Tape

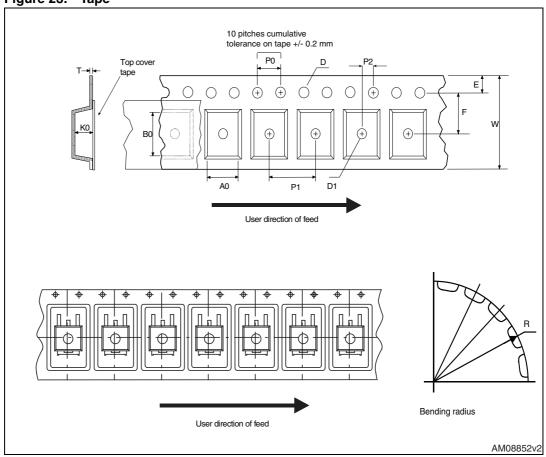
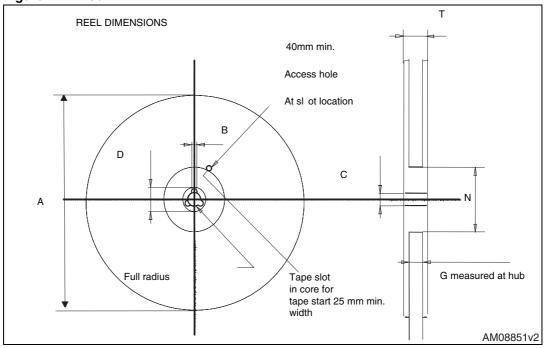


Figure 24. Reel



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# 6 Revision history

Table 13. Document revision history

Date Revision		Changes
27-Jul-2007 1		First release
09-Jul-2008	2	4: Package mechanical data has been updated.
21-Nov-2008 3		Updated Table 9 and Figure 15
20-Sep-2012	4	Minor text changes in the Description.  Updated: Section 4: Package mechanical data on page 10 and Section 5: Packaging mechanical data on page 14.

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